| Ref<br># | Hits | Search Query   | DBs   | Default<br>Operator | Plurals | Time Stamp       |
|----------|------|--|---|---------------------|---------|------------------|
| L1       | 854  | 257/88.ccls.   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT | OR                  | ON      | 2005/10/29 17:23 |
| L2       | 266  | 257/91.ccls.   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT | OR                  | ON      | 2005/10/29 17:31 |
| L3       | 2170 | 257/99-99.ccls.  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT | OR                  | ON      | 2005/10/29 17:53 |
| L4       | 1971 | 257/103.ccls.  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT | OR                  | ON      | 2005/10/29 18:10 |
| L5       |      | (plane and substrate and raised adj<br>crystal adj portion and crystal adj<br>planes and active adj layer and tilt and<br>first adj electrode and second adj<br>electrode and size).clm. | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT | OR                  | ON      | 2005/10/29 18:13 |